

SIEMENS

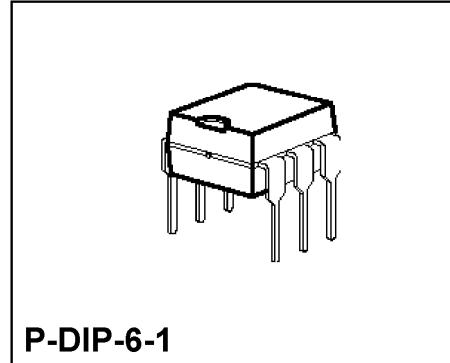
Single PNP-Operational Amplifiers

TAE 1453
TAF 1453

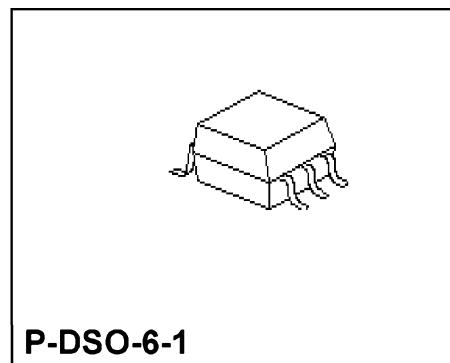
Bipolar IC

Features

- PNP input
- Supply voltage range between 3 V and 36 V
- Low current consumption, 0.25 mA typ.
- Extremely large control range
- Low output saturation voltage, almost independent of load current
- Output current up to 70 mA (100 mA max.)
- Wide common-mode range
- Wide operating temperature range (TAF 1453)
- Pin-compatible to TAA 765
- Open collector output



P-DIP-6-1



P-DSO-6-1

Applications

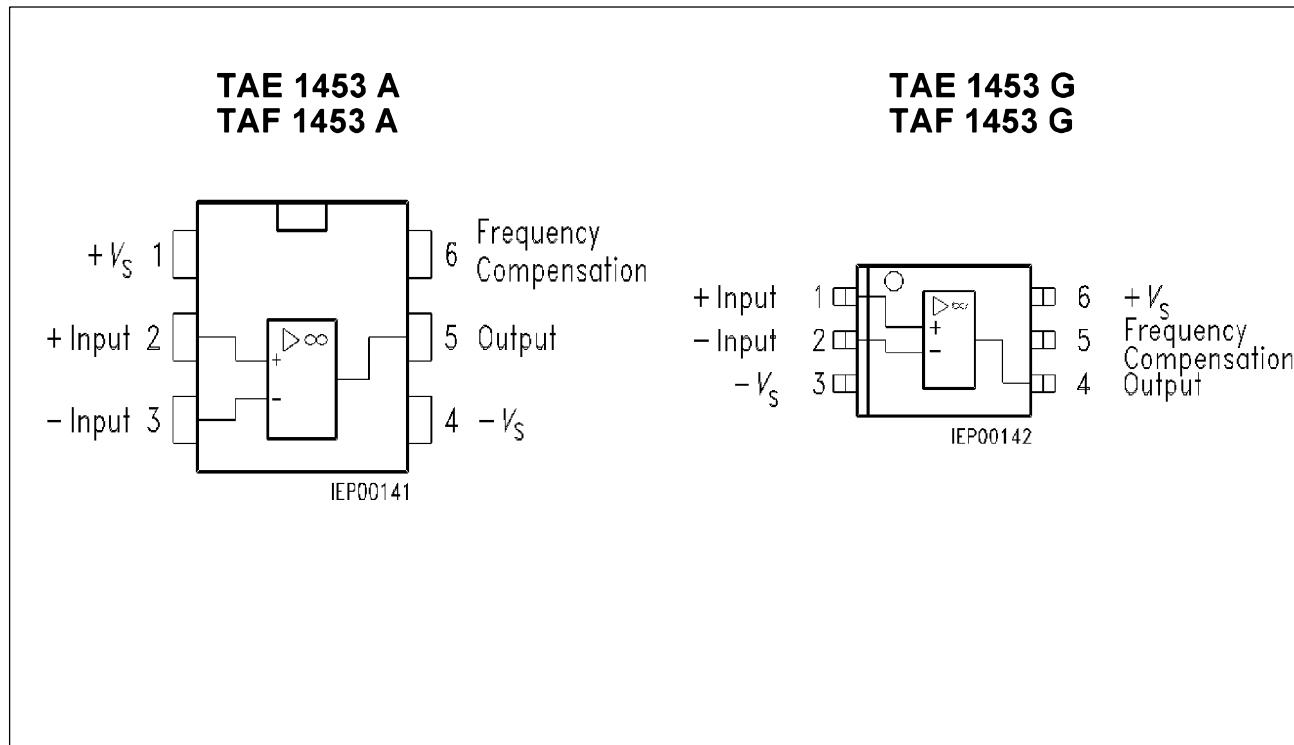
- Amplifier
- Level converter
- Driver
- Zero voltage switch
- Comparator

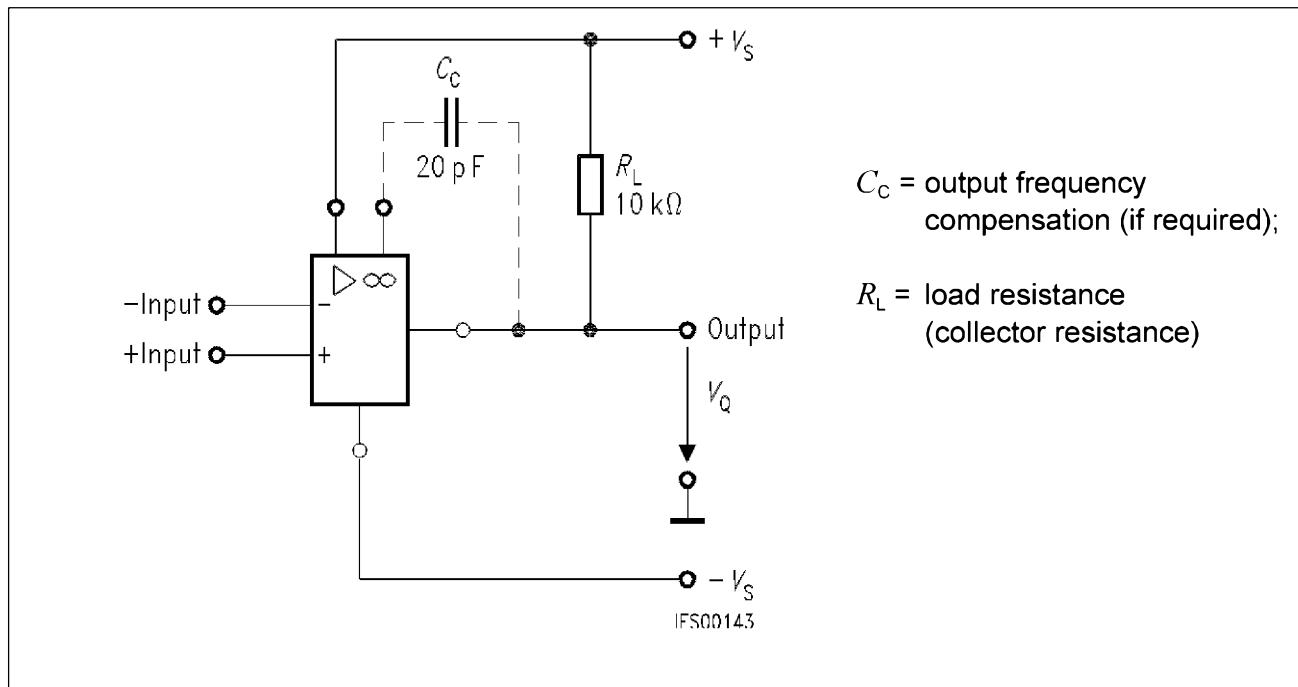
Type	Ordering Code	Package
TAE 1453 A	Q67000-A2017	P-DIP-6-1
TAE 1453 G	Q67000-A2106	P-DSO-6-1 (SMD)
TAF 1453 A	Q67000-A2269	P-DIP-6-1
TAF 1453 G	Q67000-A2209	P-DSO-6-1 (SMD)

These operational amplifiers are circuits for universal applications having a PNP-input differential stage and an open collector output. Apart from one resistor, only active components are used. The integrated regulator provides for all parameters a large degree of independence from the supply voltage.

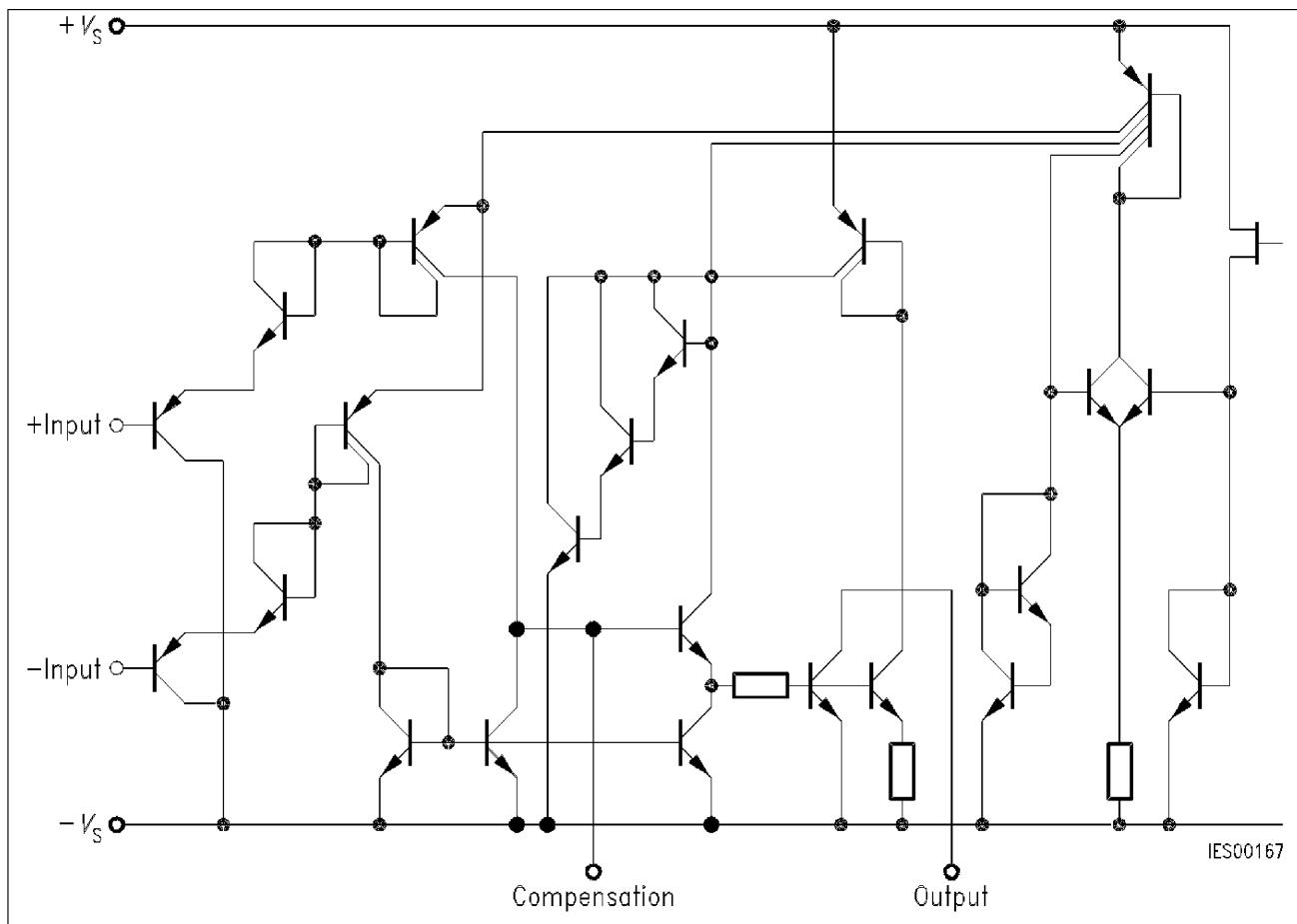
Pin Configurations

(top view)





Connection Diagram



Circuit Diagram

Absolute Maximum Ratings (TAE 1453)

Parameter	Symbol	Limit Values		Unit
Supply voltage	V_S	± 18		V
Output current	I_Q	100		mA
Differential input voltage	V_{ID}	$\pm V_S$		V
Junction temperature Storage temperature range	T_j T_{stg}	150 – 55 to 150		$^{\circ}\text{C}$ $^{\circ}\text{C}$
Thermal resistance system - air TAE 1453 A TAE 1453 G	$R_{th\ SA}$ $R_{th\ SA}$	135 200		K/W K/W

Operating Range (TAE 1453)

Supply voltage	V_S	± 2 to ± 18 (± 1.5 V with slightly increased offset voltage)	V
Ambient temperature	T_A	– 25 to 85	$^{\circ}\text{C}$

Characteristics (TAE 1453) $V_S = \pm 5$ V to ± 15 V; $R_L = 10$ k Ω , unless otherwise specified

Parameter	Symbol	Limit Values $T_A = 25$ $^{\circ}\text{C}$			Limit Values $T_A = -25$ to 85 $^{\circ}\text{C}$		Unit
		min.	typ.	max.	min.	max.	
Open-loop current consumption	I_S		0.25	0.4		0.45	mA
Input offset voltage, $R_G = 50$ Ω	V_{IO}	– 5.5		5.5	– 7	7	mV
Input offset current	I_{IO}	– 15		15	– 100	100	nA
Input current	I_I		40	150	200		nA

Characteristics (TAE 1453) (cont'd) $V_S = \pm 5 \text{ V}$ to $\pm 15 \text{ V}$; $R_L = 10 \text{ k}\Omega$, unless otherwise specified

Parameter	Symbol	Limit Values $T_A = 25 \text{ }^\circ\text{C}$			Limit Values $T_A = -25 \text{ to } 85 \text{ }^\circ\text{C}$		Unit
		min.	typ.	max.	min.	max.	
Control range $R_L = 2 \text{ k}\Omega$, $V_S = \pm 15 \text{ V}$ $R_L = 620 \Omega$, $V_S = \pm 15 \text{ V}$ $R_L = 2 \text{ k}\Omega$, $V_S = \pm 15 \text{ V}$, $f = 100 \text{ kHz}$	$V_{Q\text{ pp}}$ $V_{Q\text{ pp}}$ $V_{Q\text{ pp}}$	14.9 14.9 10		-14.7 -14.5 -10	14.9 14.9	-14.7 -14.4	V
Input impedance, $f = 1 \text{ kHz}$	Z_I		200				$\text{k}\Omega$
Open-loop voltage gain	G_{V0}	78	85		78		dB
Output reverse current	I_{QR}			10		20	μA
Common-mode input voltage range	V_{IC}	$-V_S$ -0.2		V_S -1.8	$-V_S$	V_S -2.0	V
Common-mode rejection	k_{CMR}	75	80		75		dB
Supply voltage rejection $G_V = 100$	k_{SVR}		25	100		120	$\mu\text{V/V}$
Temperature coefficient of I_{IO} $R_G = 50 \Omega$	α_{IIO}		0.1				nA/K
Temperature coefficient of V_{IO} $R_G = 50 \Omega$	α_{VIO}		6				$\mu\text{V/K}$
Slew rate for non-inverting operation	SR		20				$\text{V}/\mu\text{s}$
Slew rate for inverting operation	SR		30				$\text{V}/\mu\text{s}$

Characteristics (TAE 1453) $V_S = \pm 2.5 \text{ V}$, $R_L = 10 \text{ k}\Omega$

Parameter	Symbol	Limit Values $T_A = 25 \text{ }^\circ\text{C}$			Limit Values $T_A = -25 \text{ to } 85 \text{ }^\circ\text{C}$		Unit
		min.	typ.	max.	min.	max.	
Input offset voltage, $R_G = 50 \Omega$	V_{IO}	- 6		6	- 7.5	7.5	mV
Input offset current	I_{IO}	- 75		75	- 100	100	nA
Input current	I_I		40	150		200	nA
Open-loop voltage gain	G_{V0}	70			70		dB

Absolute Maximum Ratings (TAF 1453)

Parameter	Symbol	Limit Values		Unit
Supply voltage	V_S	± 18		V
Output current	I_Q	100		mA
Differential input voltage	V_{ID}	$\pm V_S$		V
Junction temperature	T_j	150		$^\circ\text{C}$
Storage temperature range	T_{stg}	- 55 to 125		$^\circ\text{C}$
Thermal resistance system - air	$R_{th \text{ SA}}$	135		K/W
TAF 1453 A		200		K/W
TAF 1453 G				

Operating Range (TAF 1453)

Supply voltage	V_S	$\pm 2 \text{ to } \pm 18$ ($\pm 1.5 \text{ V}$ with slightly increased offset voltage)	V
Ambient temperature	T_A	- 55 to 125	$^\circ\text{C}$

Characteristics (TAF 1453) $V_S = \pm 5 \text{ V}$ to $\pm 15 \text{ V}$; $R_L = 10 \text{ k}\Omega$, unless otherwise specified

Parameter	Symbol	Limit Values $T_A = 25 \text{ }^\circ\text{C}$			Limit Values $T_A = -55 \text{ to } 125 \text{ }^\circ\text{C}$		Unit
		min.	typ.	max.	min.	max.	
Open-loop current consumption (Output in H state)	I_S		0.25	0.35		0.45	mA
Input offset voltage, $R_G = 50 \Omega$	V_{IO}	-4		4	-6	6	mV
Input offset voltage Input current	I_{IO} I_I	-10	40	10 100	-75	75 150	nA nA
Control range $R_L = 2 \text{ k}\Omega$, $V_S = \pm 15 \text{ V}$ $R_L = 620 \Omega$, $V_S = \pm 15 \text{ V}$ $R_L = 2 \text{ k}\Omega$, $V_S = \pm 15 \text{ V}$, $f = 100 \text{ kHz}$	$V_{Q\text{ pp}}$ $V_{Q\text{ pp}}$ $V_{Q\text{ pp}}$	14.9 14.9 10		-14.7 -14.5 -10	14.9 14.9	-14.7 -14.4	V V V
Input impedance, $f = 1 \text{ kHz}$	Z_I		200				k Ω
Open-loop voltage gain	G_{V0}	80	85		75		dB
Output reverse current	I_{QR}			1		5	μA
Common-mode input voltage range	V_{IC}	$-V_S$ -0.3		V_S -1.5	$-V_S$	V_S -1.8	V
Common-mode rejection	k_{CMR}	80	85		75		dB
Supply voltage rejection $G_V = 100$	k_{SVR}		25	100		100	$\mu\text{V/V}$
Temperature coefficient of I_{IO} $R_G = 50 \Omega$	α_{IO}		0.1	0.8			nA/K
Temperature coefficient of V_{IO} $R_G = 50 \Omega$	α_{VIO}		6	25			$\mu\text{V/K}$
Slew rate for non-inverting operation Slew rate for inverting operation	SR SR		20 30				V/ μs V/ μs

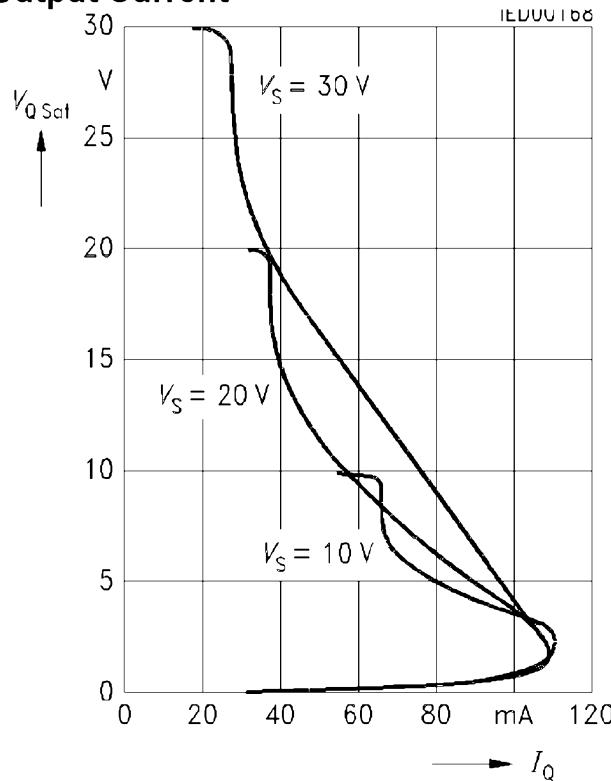
Characteristics (TAF 1453) $V_S = \pm 2.5 \text{ V}$, $R_L = 10 \text{ k}\Omega$

Parameter	Symbol	Limit Values $T_A = 25 \text{ }^\circ\text{C}$			Limit Values $T_A = -55 \text{ to } 125 \text{ }^\circ\text{C}$		Unit
		min.	typ.	max.	min.	max.	
Input offset voltage, $R_G = 50 \Omega$	V_{IO}	- 4		4	- 6	6	mV
Input offset voltage Input current	I_{IO} I_I	- 50	40	50 100	- 75	75 150	nA nA
Open-loop voltage gain	G_{V0}	75			70		dB

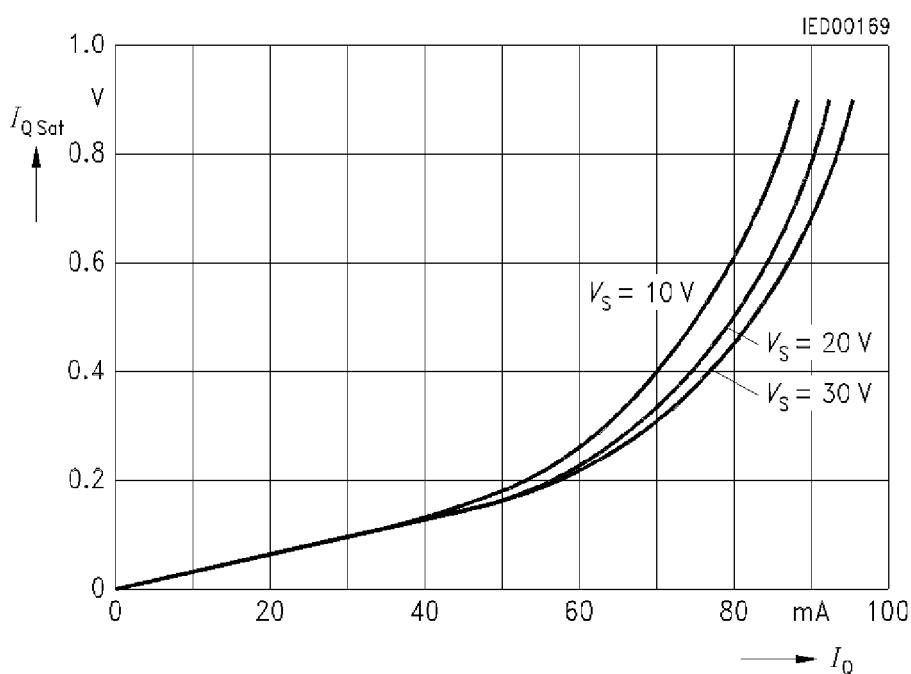
Typical Characteristics of Electrical Parameters

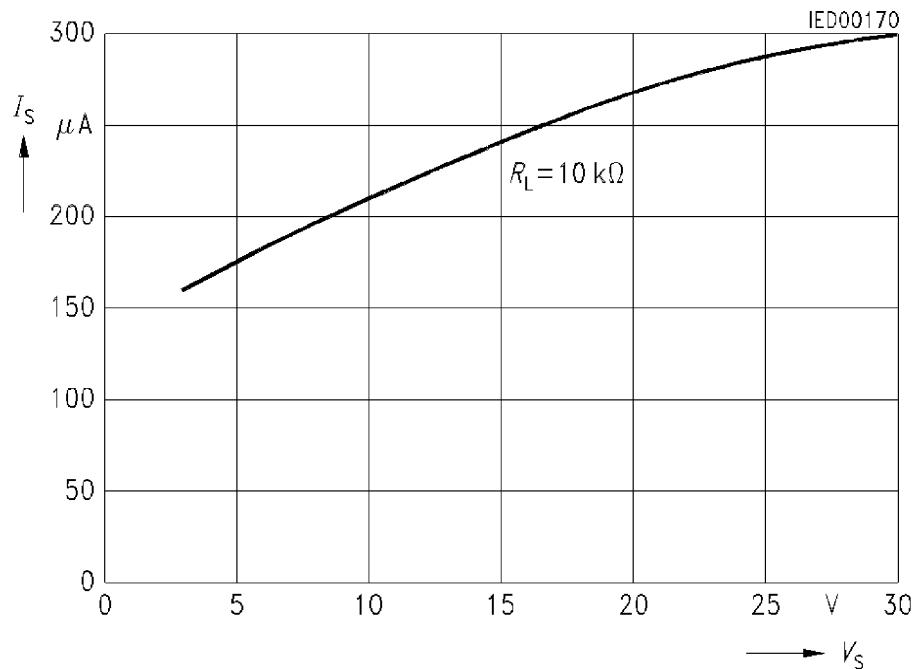
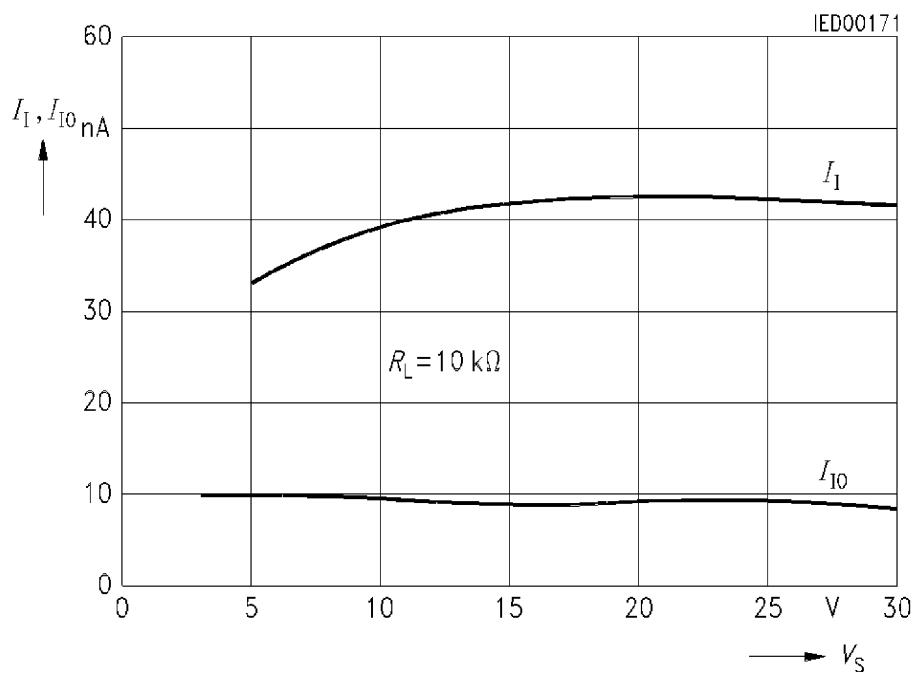
Load Characteristics

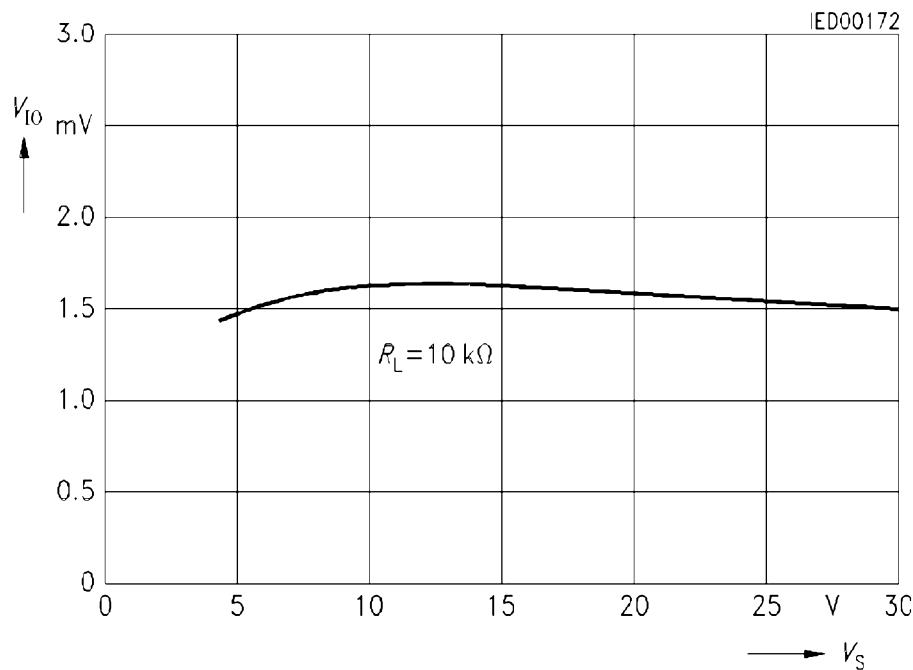
Output Saturation Voltage versus Output Current



Output Saturation Voltage versus Output Current



Supply Current versus Supply Voltage**Input Current and Input Offset Current versus Supply Voltage**

Input Offset Voltage versus Supply Voltage **V_{IO} Behavior at Low Operating Voltages
Input Offset Voltage versus Supply Voltage**